

SSCE18V11D3

1-line Uni-directional Micro Packaged TVS Diodes for ESD Protection

Description

The SSCE18V11D3 is designed to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time provide best in class protection on designs that are exposed to ESD. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space comes at a premium.

It has been specifically designed to protect sensitive components which are connected to data and transmission lines from overvoltage caused by ESD (electrostatic discharge), and EFT (electrical fast transients).

Feature

- \Rightarrow 340W peak pulse power (t_P = 8/20µs)
- ♦ SOD-523 Package
- ♦ Working voltage: 18V
- Low clamping voltage
- ♦ Low capacitance
- ♦ Low leakage current
- ♦ Response Time is<1 ns</p>
- ♦ RoHS compliant
- ♦ Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test

Air discharge: ±30kV

Contact discharge: ±30kV

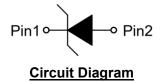
-IEC 61000-4-5(Surge) 10A(8/20µs)

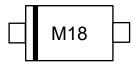
Mechanical data

- ♦ Lead finish:100% matte Sn (Tin)
- ♦ Mounting position: Any
- ♦ Qualified max reflow temperature:260 °C
- ♦ Device meets MSL 3 requirements
- ♦ Pure tin plating: 7 ~ 17 um
- ♦ Pin flatness: ≤3mil

PIN configuration







Marking (Top View)

Applications

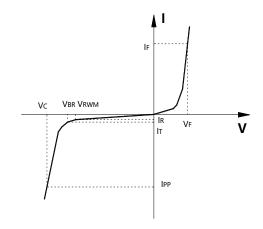
- ♦ Cellular Handsets and Accessories
- ♦ Personal Digital Assistants
- ♦ Notebooks and Handhelds
- Portable Instrumentation, Digital Cameras
- Peripherals, Audio Players, Industrial Equipment

2 / 5



• Electronic Parameter

Symbol	Parameter		
V_{RWM}	Peak Reverse Working Voltage		
I _R	Reverse Leakage Current @ V _{RWM}		
V _{BR}	Breakdown Voltage @ I⊤		
Ι _Τ	Test Current		
I _{PP}	Maximum Reverse Peak Pulse Current		
Vc	Clamping Voltage @ IPP		
P _{PP}	Peak Pulse Power		
Сл	Junction Capacitance		



Absolute maximum rating @T_A=25℃

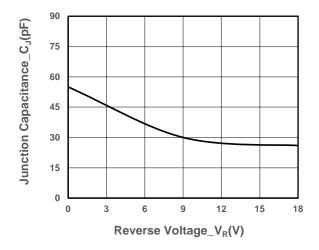
Parameter		Symbol	Value	Unit
Peak Pulse Power (8/20µs)		P _{PP}	340	W
Peak Pulse Current (8/20µs)		I _{PP}	10	Α
ESD Rating per IEC61000-4-2:	Contact		30	KV
	Air	V _{ESD}	30	
Storage Temperature		T _{STG}	-55/+150	$^{\circ}$
Operating Temperature		TJ	-55/+125	$^{\circ}$ C

• Electrical Characteristics @T_A=25℃

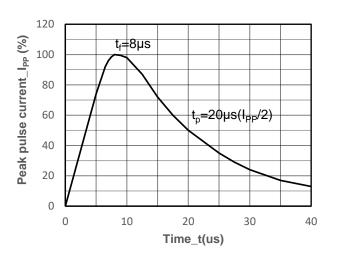
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Peak Reverse Working Voltage	V_{RWM}				18	٧
Breakdown Voltage	V _{BR}	I⊤ = 1mA	19		24	V
Reverse Leakage Current	I _R	V _{RWM} = 18V			0.1	μΑ
Clamping Voltage	Vc	$I_{PP} = 1A$, $t_P = 8/20 \mu s$			28	٧
Clamping Voltage	Vc	$I_{PP} = 10A$, $t_P = 8/20 \mu s$			34	V
Junction Capacitance	СJ	V _R = 0V, f = 1MHz			70	pF



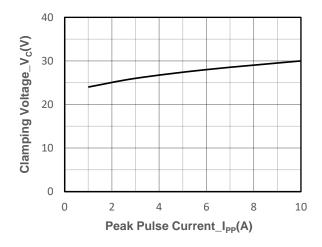
• Typical Performance Characteristics



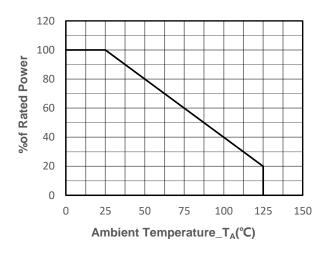
Junction Capacitance vs. Reverse Voltage



8/20µs Pulse Waveform



Clamping Voltage vs. Peak Pulse Current



Power derating vs. Ambient temperature



• Package Information

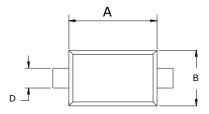
Ordering Information

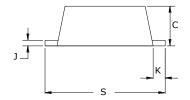
Device	Package	Qty per Reel	Reel Size
SSCE18V11D3	SOD-523	3000	7 Inch

Mechanical Data

Case: SOD-523

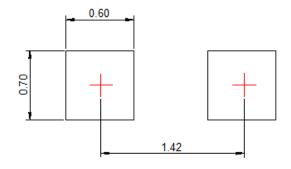
Case Material: Molded Plastic. UL Flammability





DIM	Millimeters			
	Min	Max		
Α	1.10	1.30		
В	0.75	0.85		
С	0.51	0.70		
D	0.25	0.35		
J	0.08	0.15		
K	0.15	0.25		
s	1.50	1.70		

Recommended Pad outline (Unit: mm)





DISCLAIMER

AFSEMI RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. AFSEMI DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICIENCE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

THE GRAPHS PROVIDED IN THIS DOCUMENT ARE STATISTICAL SUMMARIES BASED ON A LIMITED NUMBER OF SAMPLES AND ARE PROVIDED FOR INFORMATIONAL PURPOSE ONLY. THE PERFORMANCE CHARACTERISTICS LISTED IN THEM ARE NOT TESTED OR GUARANTEED. IN SOME GRAPHS, THE DATA PRESENTED MAY BE OUTSIDE THE SPECIFIED OPERATING RANGE (E.G. OUTSIDE SPECIFIED POWER SUPPLY RANGE) AND THEREFORE OUTSIDE THE WARRANTED RANGE.